



#### Product Summary

$V_{(BR)DSS}$	$R_{DS(on)TYP}$	$I_D$
30V	4.3m $\Omega$ @10V	60A
	5.7m $\Omega$ @4.5V	

#### Feature

- Trench Technology Power MOSFET
- Low  $R_{DS(ON)}$
- Low Gate Charge
- Low Gate Resistance
- 100% UIS Tested

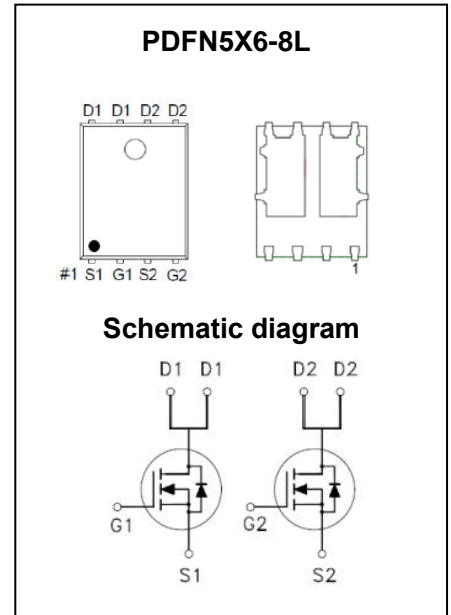
#### Application

- Power Switching Application

#### MARKING:



M041ND03L = Device Code  
 XX = Date Code  
 Solid Dot = Green Indicator



#### ABSOLUTE MAXIMUM RATINGS ( $T_A = 25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain - Source Voltage	$V_{DS}$	30	V
Gate - Source Voltage	$V_{GS}$	$\pm 20$	V
Continuous Drain Current <sup>1</sup>	$T_C = 25^\circ\text{C}$	$I_D$	60 A
	$T_C = 100^\circ\text{C}$	$I_D$	37 A
Pulsed Drain Current <sup>2</sup>	$I_{DM}$	240	A
Single Pulsed Avalanche Current <sup>3</sup>	$I_{AS}$	32	A
Single Pulsed Avalanche Energy <sup>3</sup>	$E_{AS}$	256	mJ
Power Dissipation <sup>5</sup>	$T_C = 25^\circ\text{C}$	$P_D$	44 W
Thermal Resistance from Junction to Ambient <sup>6</sup>	$T_A = 25^\circ\text{C}$	$R_{\theta JA}$	50 $^\circ\text{C/W}$
Thermal Resistance from Junction to Case		$R_{\theta JC}$	2.8 $^\circ\text{C/W}$
Junction Temperature	$T_J$	150	$^\circ\text{C}$
Storage Temperature	$T_{STG}$	-55~ +150	$^\circ\text{C}$

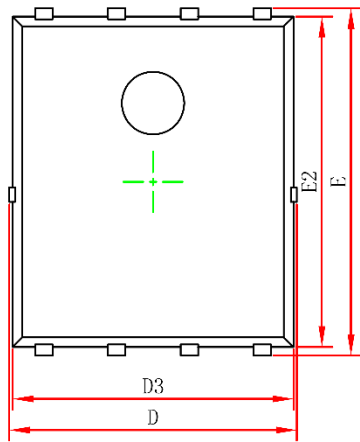
## MOSFET ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Test Condition	Min	Type	Max	Unit
<b>Off Characteristics</b>						
Drain - Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS} = 0V, I_D = 250\mu A$	30			V
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS} = 30V, V_{GS} = 0V$			1	$\mu A$
Gate - Body Leakage Current	$I_{GSS}$	$V_{GS} = \pm 20V, V_{DS} = 0V$			$\pm 100$	nA
<b>On Characteristics<sup>4</sup></b>						
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 250\mu A$	1.3	1.5	3.0	V
Drain-source On-resistance	$R_{DS(on)}$	$V_{GS} = 10V, I_D = 20A$		4.3	5.6	m $\Omega$
		$V_{GS} = 4.5V, I_D = 15A$		5.7	7.5	
<b>Dynamic Characteristics</b>						
Input Capacitance	$C_{iss}$	$V_{DS} = 15V, V_{GS} = 0V, f = 1MHz$		2650		pF
Output Capacitance	$C_{oss}$			341		
Reverse Transfer Capacitance	$C_{rss}$			272		
Gate Resistance	$R_g$	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$		2.5		$\Omega$
<b>Switching Characteristics</b>						
Total Gate Charge	$Q_g$	$V_{DD} = 15V, V_{GS} = 10V, I_D = 20A$		57		nC
Gate-source Charge	$Q_{gs}$			7.7		
Gate-drain Charge	$Q_{gd}$			12.4		
Turn-on Delay Time	$t_{d(on)}$	$V_{DD} = 15V, V_{GS} = 10V, I_D = 22.5A$ $R_G = 3\Omega$		10		ns
Turn-on Rise Time	$t_r$			65		
Turn-off Delay Time	$t_{d(off)}$			40		
Turn-off Fall Time	$t_f$			90		
<b>Source - Drain Diode Characteristics</b>						
Diode Forward Voltage <sup>4</sup>	$V_{SD}$	$V_{GS} = 0V, I_S = 10A$			1.2	V

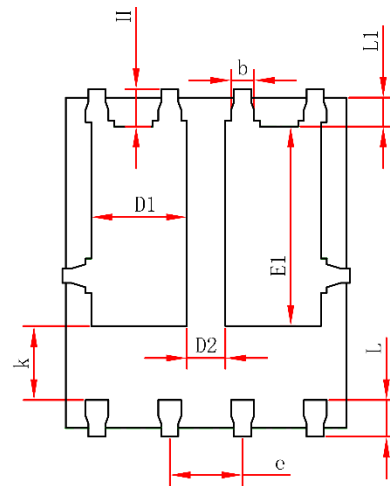
Notes :

- 1.The maximum current rating is limited by package.And device mounted on a large heatsink
- 2.Pulse Test : Pulse Width  $\leq 10\mu s$ , duty cycle  $\leq 1\%$ .
3. $E_{AS}$  condition:  $V_{DD} = 15V, V_{GS} = 10V, L = 0.5mH, R_G = 25\Omega$  Starting  $T_J = 25^\circ\text{C}$ .
- 4.Pulse Test : Pulse Width  $\leq 300\mu s$ , duty cycle  $\leq 2\%$ .
- 5.The power dissipation  $P_D$  is limited by  $T_{J(MAX)} = 150^\circ\text{C}$ .And device mounted on a large heatsink
- 6.Device mounted on  $1in^2$  FR-4 board with 2oz. Copper, in a still air environment with  $T_A = 25^\circ\text{C}$ .

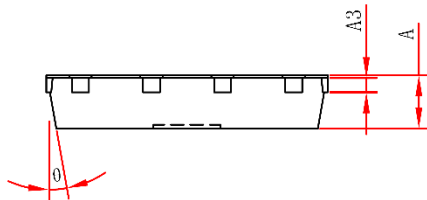
## PDFN5X6-8L Package Information



Top View  
[顶视图]



Bottom View  
[背视图]



Side View  
[侧视图]

Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.900	1.100	0.035	0.043
A3	0.210	0.340	0.008	0.013
D	4.900	5.100	0.193	0.201
E	5.900	6.100	0.232	0.240
D1	1.470	1.870	0.058	0.074
D2	0.470	0.870	0.019	0.034
E1	3.340	3.640	0.131	0.143
D3	4.800	5.000	0.189	0.197
E2	5.674	5.826	0.223	0.229
k	1.100	-	0.043	-
b	0.300	0.500	0.012	0.020
e	1.270TYB		0.050TYB	
L	0.510	0.710	0.020	0.028
L1	0.424	0.576	0.017	0.023
H	0.549	0.726	0.022	0.029
θ	8°	12°	8°	12°

**Attention:**

- GreenPower Electronics reserves the right to improve product design function and reliability without notice.
- Any and all semiconductor products have certain probability to fail or malfunction, which may result in personal injury, death or property damage. Customer are solely responsible for providing adequate safe measures when design their systems.
- GreenPower Electronics products belong to consumer electronics or other civilian electronic products.